SGM8584
Single-Supply, Quad Rail-to-Rail I/O Precision Operational Amplifier

PRODUCT DESCRIPTION

The SGM8584 is a quad rail-to-rail input and output precision operational amplifier which has low input offset voltage, and bias current. It is guaranteed to operate from 2.5V to 5.5V single supply.

The rail-to-rail input and output swings provided by the SGM8584 make both high-side and low-side sensing easy. The combination of characteristics makes the SGM8584 good choices for temperature, position and pressure sensors, medical equipment and strain gauge amplifiers, or any other 2.5V to 5.5V application requiring precision and long term stability.

The SGM8584 is specified for the extended industrial/ automotive (-40℃ to +125℃) temperature range. The SGM8584 comes in the Green SOIC-14 and TSSOP-14 packages.

APPLICATIONS

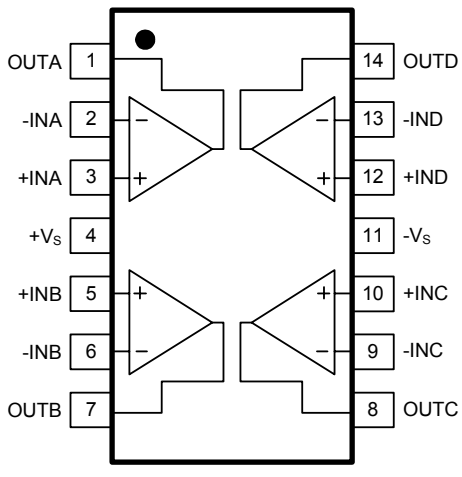
Temperature Measurements
Pressure Sensors
Precision Current Sensing
Electronic Scales
Strain Gage Amplifiers
Medical Instrumentation
Thermocouple Amplifiers
Handheld Test Equipment

FEATURES

- **Low Offset Voltage: 25μV (TYP)**
- **Rail-to-Rail Input and Output Swing**
- **2.5V to 5.5V Single Supply Operation**
- **Voltage Gain: 135dB (TYP) at +5V**
- **PSRR: 115dB (TYP)**
- **CMRR: 92dB (TYP)**
- **Low Input Bias Current: 60pA**
- **Low Supply Current: 430μA/Channel**
- **Overload Recovery Time: 30μs (at V_S = +5V)**
- **No External Capacitors Required**
- **-40℃ to +125℃ Operating Temperature Range**
- **Available in Green SOIC-14 and TSSOP-14 Packages**

PIN CONFIGURATIONS (Top View)

SGM8584



SOIC-14/TSSOP-14

PACKAGE/ORDERING INFORMATION

MODEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
SGM8584	SGM8584XS14G/TR	SOIC-14	Tape and Reel, 2500	SGM8584XS14
	SGM8584XTS14G/TR	TSSOP-14	Tape and Reel, 3000	SGM8584XTS14

ABSOLUTE MAXIMUM RATINGS

Supply Voltage. 6V
Input Voltage . . . . . $-V_S$ to $(+V_S)$ + 0.1V
Differential Input Voltage. . . . . -5V to 5V
Storage Temperature Range . . . . . -65℃ to +150℃
Junction Temperature. . . . . 150℃
Operating Temperature Range. . . . . -40℃ to +125℃
Lead Temperature Range (Soldering 10 sec)
. . . . . 260℃
ESD Susceptibility
HBM (TSSOP-14) 8000V
HBM (SOIC-14) 7000V
MM. 400V

NOTE:
Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don’t pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGMICRO reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SGMICRO sales office to get the latest datasheet.

ELECTRICAL CHARACTERISTICS

(V_S = +5V, V_{CM} = +2.5V, V_O = +2.5V, T_A = +25℃, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS					
Input Offset Voltage (V_{OS})			25	100	μV
	-40℃ ≤ T_A ≤ +125℃			110	
Input Bias Current (I_B)			60		pA
Input Offset Current (I_{OS})			50		pA
Input Voltage Range		0		5	V
Common-Mode Rejection Ratio (1) (CMRR)	V_{CM} = 0V to 5V	88	92		dB
	-40℃ ≤ T_A ≤ +125℃	77			
Large Signal Voltage Gain (A_{VO})	R_L = 10kΩ, V_O = 0.3V to 4.7V	120	135		dB
	-40℃ ≤ T_A ≤ +125℃	104			
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta_T$)	-40℃ ≤ T_A ≤ +125℃		150		nV/℃
OUTPUT CHARACTERISTICS					
Output Voltage High (V_{OH})	R_L = 100kΩ to -V_S	4.9	4.998		V
	-40℃ ≤ T_A ≤ +125℃	4.894			
	R_L = 10kΩ to -V_S	4.9	4.994		V
	-40℃ ≤ T_A ≤ +125℃	4.888			
Output Voltage Low (V_{OL})	R_L = 100kΩ to +V_S		3.5	6	mV
	-40℃ ≤ T_A ≤ +125℃			8	
	R_L = 10kΩ to +V_S		7	10	mV
	-40℃ ≤ T_A ≤ +125℃			23	
Short Circuit Limit (I_{SC})	V_O = 2.5V, R_L = 10Ω to GND	30	40		mA
	-40℃ ≤ T_A ≤ +125℃	22			
POWER SUPPLY					
Power Supply Rejection Ratio (1) (PSRR)	V_S = 2.5V to 5.5V	90	115		dB
	-40℃ ≤ T_A ≤ +125℃	80			
Quiescent Current / per Channel (I_Q)	V_O = +V_S/2		430	555	μA
	-40℃ ≤ T_A ≤ +125℃			710	
DYNAMIC PERFORMANCE					
Gain-Bandwidth Product (GBP)	A_V = +100		1.5		MHz
Slew Rate (SR)	A_V = +1, R_L = 10kΩ, 2V Output Step		0.9		V/μs
Overload Recovery Time	A_V = -100, R_L = 10kΩ, V_{IN} = 200mV (RET to GND)		0.03		ms
NOISE PERFORMANCE					
Voltage Noise (e_n p-p)	0.1Hz to 10Hz		1.4		μV_{P-P}
Voltage Noise Density (e_n)	f = 1kHz		78		$nV/\sqrt{Hz}$

NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

ELECTRICAL CHARACTERISTICS

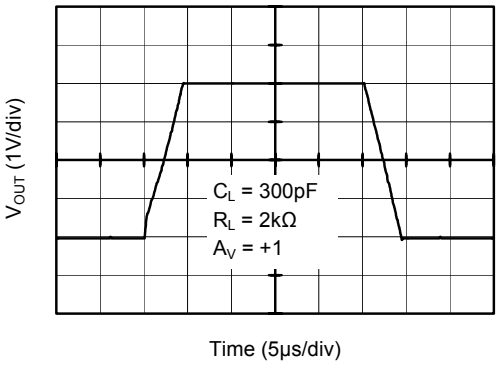
(V_S = +2.5V, V_{CM} = +1.25V, V_O = +1.25V, T_A = +25℃, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
INPUT CHARACTERISTICS					
Input Offset Voltage (V_{OS})			25	100	μV
	-40℃ ≤ T_A ≤ +125℃			120	
Input Bias Current (I_B)			30		pA
Input Offset Current (I_{OS})			20		pA
Input Voltage Range		0		2.5	V
Common-Mode Rejection Ratio (1) (CMRR)	V_{CM} = 0V to 2.5V	79	85		dB
	-40℃ ≤ T_A ≤ +125℃	70			
Large Signal Voltage Gain (A_{VO})	R_L = 10kΩ, V_O = 0.3V to 2.4V	120	130		dB
	-40℃ ≤ T_A ≤ +125℃	104			
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta_T$)	-40℃ ≤ T_A ≤ +125℃		150		nV/℃
OUTPUT CHARACTERISTICS					
Output Voltage High (V_{OH})	R_L = 100kΩ to -V_S	2.4	2.499		V
	-40℃ ≤ T_A ≤ +125℃	2.38			
	R_L = 10kΩ to -V_S	2.4	2.497		V
	-40℃ ≤ T_A ≤ +125℃	2.389			
Output Voltage Low (V_{OL})	R_L = 100kΩ to +V_S		4	6	mV
	-40℃ ≤ T_A ≤ +125℃			7	
	R_L = 10kΩ to +V_S		6	8	mV
	-40℃ ≤ T_A ≤ +125℃			12	
Short Circuit Limit (I_{SC})	V_O = 1.25V, R_L = 10Ω to GND	20	28		mA
	-40℃ ≤ T_A ≤ +125℃	13			
POWER SUPPLY					
Power Supply Rejection Ratio (1) (PSRR)	V_S = 2.5V to 5.5V	90	115		dB
	-40℃ ≤ T_A ≤ +125℃	80			
Quiescent Current / per Channel (I_Q)	V_O = +V_S/2		430	550	μA
	-40℃ ≤ T_A ≤ +125℃			710	
DYNAMIC PERFORMANCE					
Gain-Bandwidth Product (GBP)	A_V = +100		1.5		MHz
Slew Rate (SR)	A_V = +1, R_L = 10kΩ, 2V Output Step		1.0		V/μs
Overload Recovery Time	A_V = -100, R_L = 10kΩ, V_{IN} = 200mV (RET to GND)		0.02		ms
NOISE PERFORMANCE					
Voltage Noise (e_n p-p)	0.1Hz to 10Hz		1.7		μV_{P-P}
Voltage Noise Density (e_n)	f = 1kHz		108		$nV/\sqrt{Hz}$

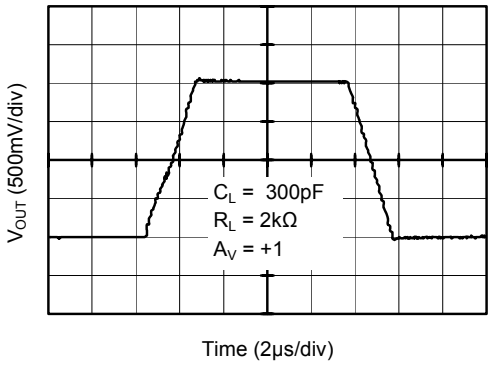
NOTE 1: PSRR and CMRR are affected by the matching between external gain-setting resistor ratios.

TYPICAL PERFORMANCE CHARACTERISTICS

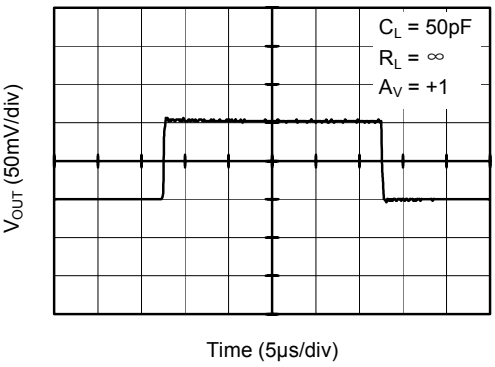
Large Signal Transient Response at +5V



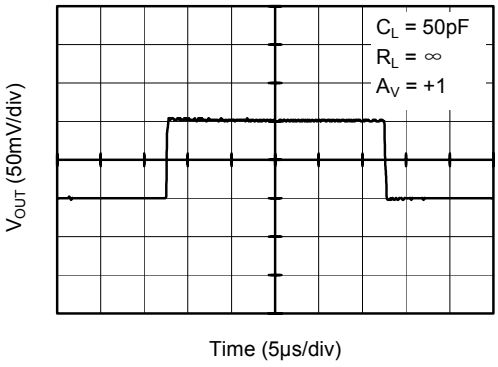
Large Signal Transient Response at +2.5V



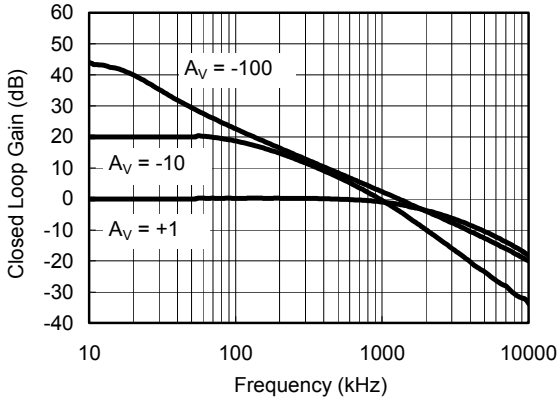
Small Signal Transient Response at +5V



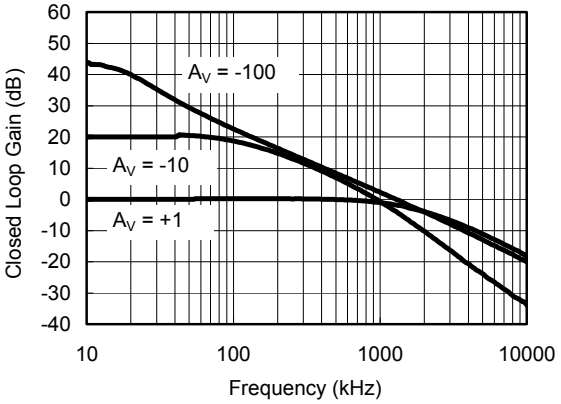
Small Signal Transient Response at +2.5V



Closed Loop Gain vs. Frequency at +5V

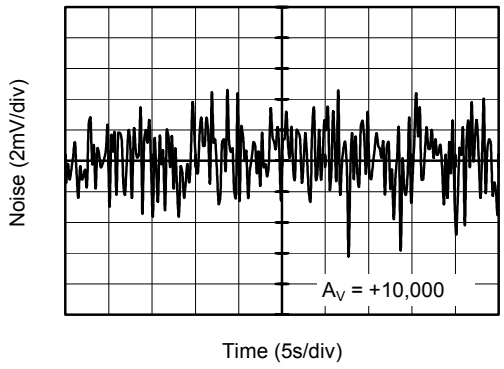


Closed Loop Gain vs. Frequency at +2.5V

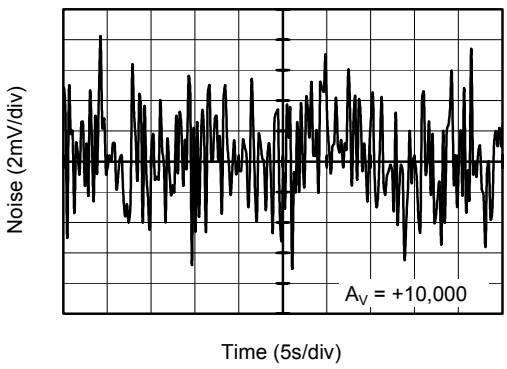


TYPICAL PERFORMANCE CHARACTERISTICS

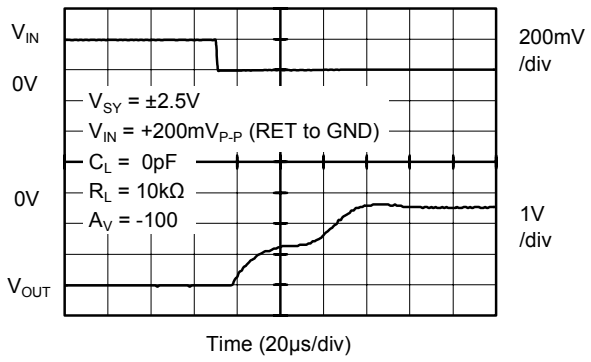
0.1Hz to 10Hz Noise at +5V



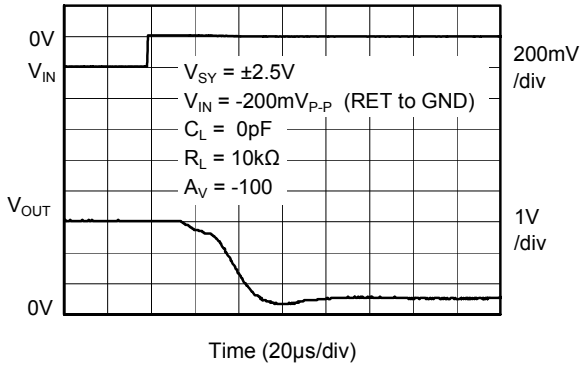
0.1Hz to 10Hz Noise at +2.5V



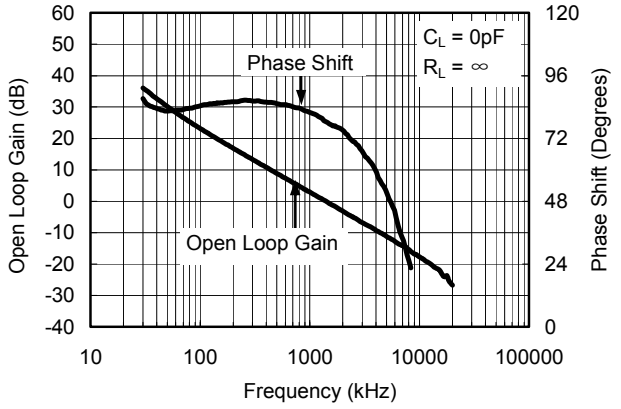
Negative Overvoltage Recovery



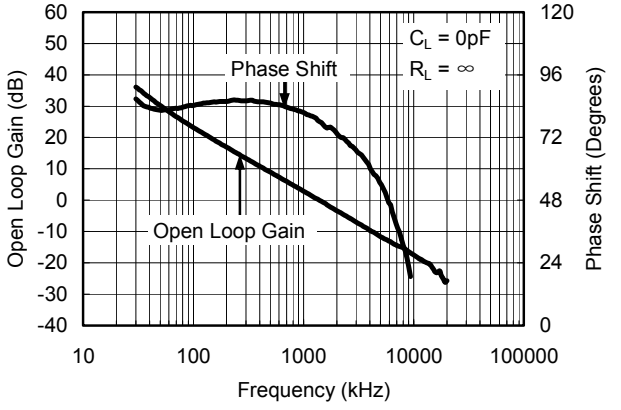
Positive Overvoltage Recovery



Open Loop Gain, Phase Shift vs. Frequency at +5V

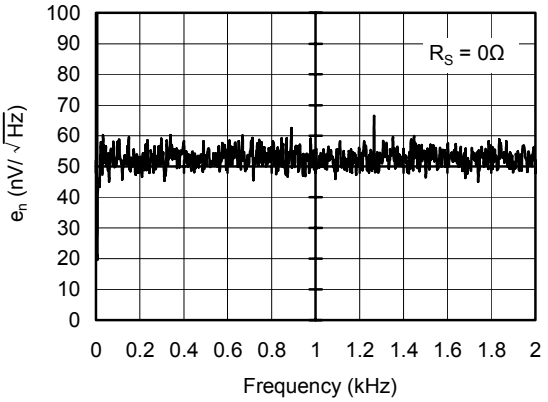


Open Loop Gain, Phase Shift vs. Frequency at +2.5V

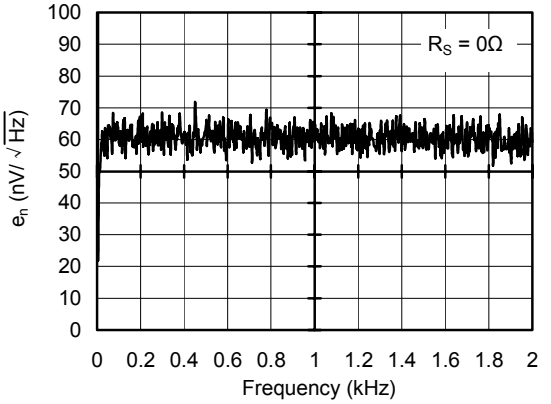


TYPICAL PERFORMANCE CHARACTERISTICS

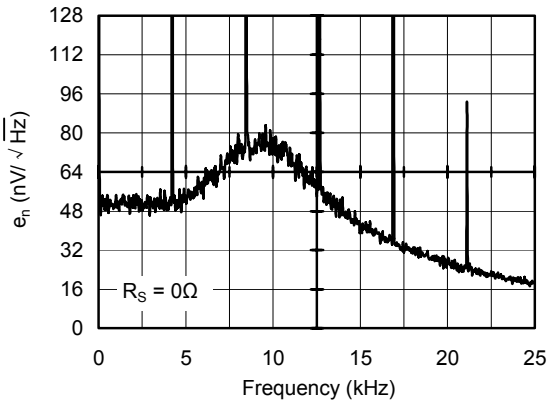
Voltage Noise Density at +5V
from 0.1Hz to 2.5kHz



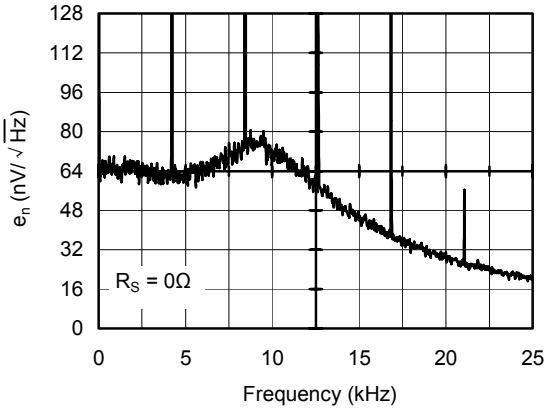
Voltage Noise Density at +2.5V
from 0.1Hz to 2.5kHz



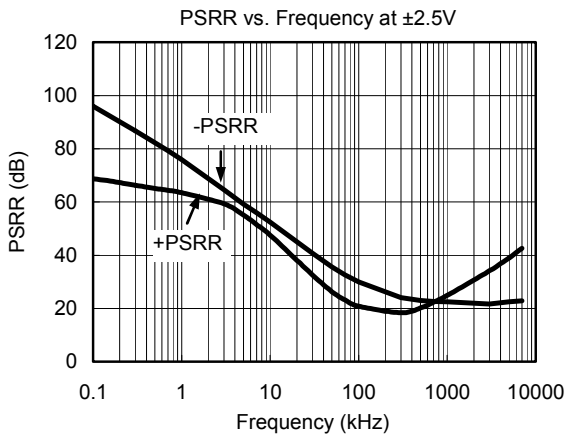
Voltage Noise Density at +5V
from 0.1Hz to 25kHz



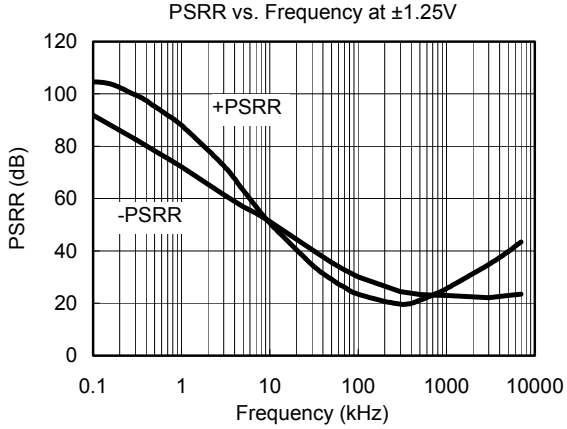
Voltage Noise Density at +2.5V
from 0.1Hz to 25kHz



PSRR vs. Frequency at ±2.5V

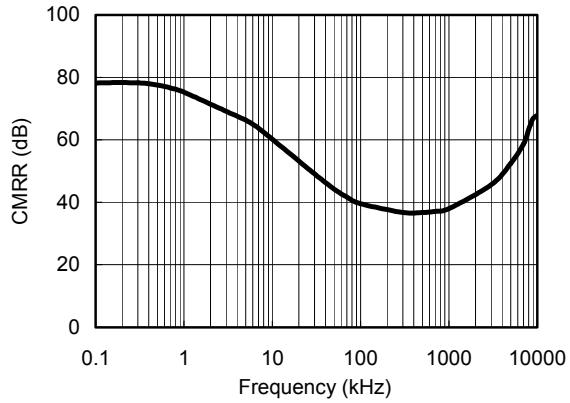


PSRR vs. Frequency at ±1.25V

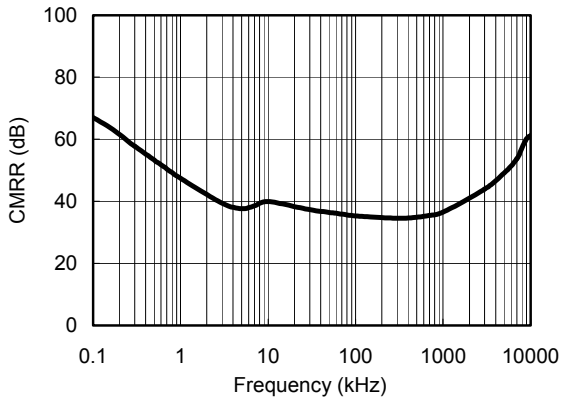


TYPICAL PERFORMANCE CHARACTERISTICS

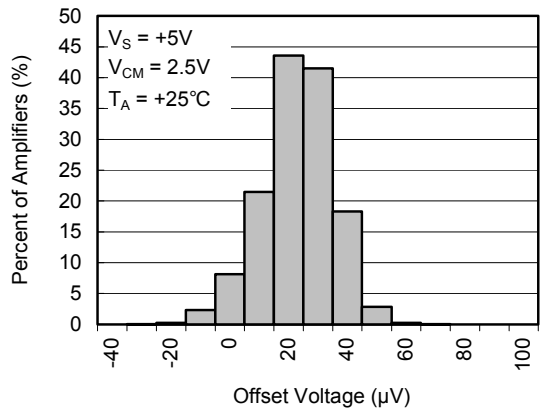
CMRR vs. Frequency at +5V



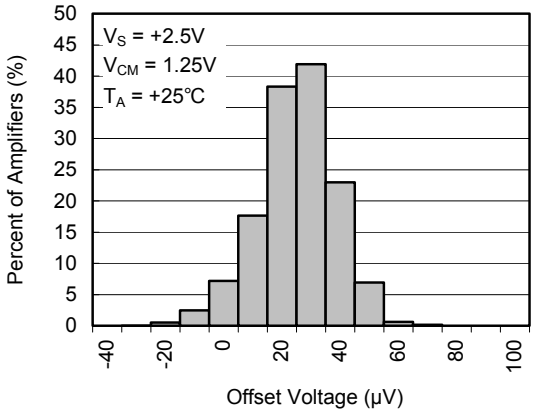
CMRR vs. Frequency at +2.5V



Offset Voltage Production Distribution at +5V

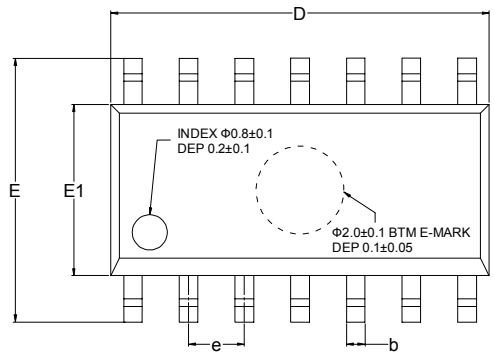


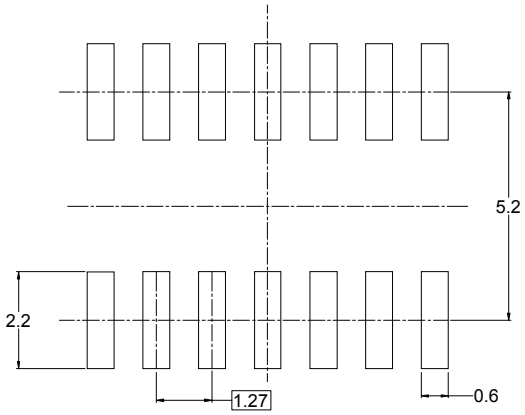
Offset Voltage Production Distribution at +2.5V



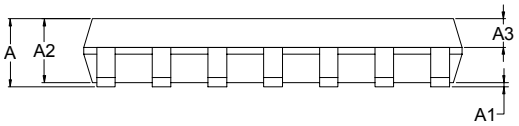
PACKAGE OUTLINE DIMENSIONS

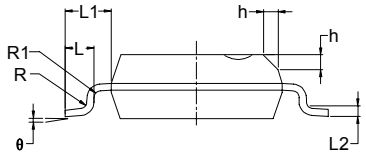
SOIC-14





RECOMMENDED LAND PATTERN (Unit: mm)

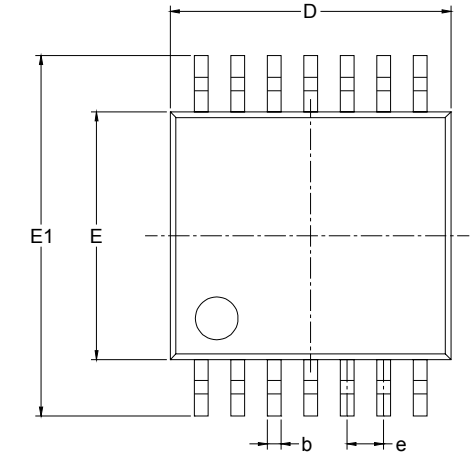


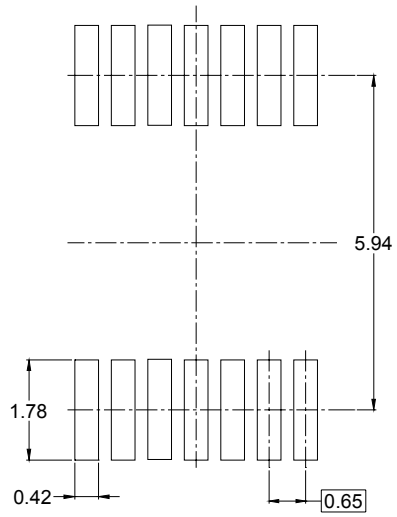


Symbol	Dimensions In Millimeters			Dimensions In Inches		
	MIN	MOD	MAX	MIN	MOD	MAX
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
e	1.27 BSC			0.050 BSC		
L	0.45		0.80	0.018		0.032
L1	1.04 REF			0.040 REF		
L2	0.25 BSC			0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°

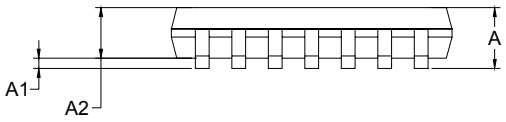
PACKAGE OUTLINE DIMENSIONS

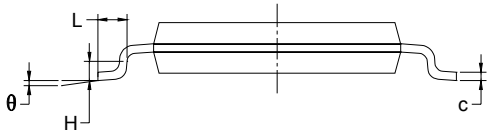
TSSOP-14





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A		1.100		0.043
A1	0.050	0.150	0.002	0.006
A2	0.800	1.000	0.031	0.039
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.900	5.100	0.193	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650 BSC		0.026 BSC	
L	0.500	0.700	0.02	0.028
H	0.25 TYP		0.01 TYP	
θ	1°	7°	1°	7°

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